

L Numb r	Hits	Search T xt	DB	Time stamp
160	1	6235600.URPN.	USPAT	2002/09/20 13:55
161	4	("5885877" "5920782" "5972783" "5994175").PN.	USPAT	2002/09/20 13:55
-	0	20020076877A1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 10:53
-	2	"20020076877"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:00
-	36	mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and liner and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:05
-	2	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and liner and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) same (polysilicon or poly-silicon) same liner same (spacer or sidewall) same (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:05
-	438	mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:05
-	61	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) same (polysilicon or poly-silicon) same oxide same (spacer or sidewall) same (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:08
-	9	((mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator r insulating r dielectric) same (p lysilic n or p ly-silicon) sam oxide sam (spacer r sid wall) sam (interl vel or int rlayer r int r-level r inter-lay r))) and liner	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:06

-	9	((mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) same (polysilicon or poly-silicon) same oxide same (spacer or sidewall) same (interlevel or interlayer or inter-level or inter-layer))) and liner) and (liner near10 oxide)	USPAT; US-PGPUB; EPO; JP ; DERWENT; IBM_TDB	2002/09/19 11:07
-	48	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) near100 (polysilicon or poly-silicon) near "100" oxide near100 (spacer or sidewall) near100 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:09
-	10	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) near50 (polysilicon or poly-silicon) near50 oxide near50 (spacer or sidewall) near50 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:11
-	2	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and (((insulator or insulating or dielectric) near30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer)) near30 liner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:12
-	10	(mosfet and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and oxide and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and ((insulator or insulating or dielectric) near30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:12
-	64	((insulator or insulating or dielectric) near30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:14

-	4	((insulator or insulating r di l ctric) n ar30 (p lysilicon r p ly-silic n) n ar30 oxid near30 (spac r or sidewall) n ar30 (int rl v l or int rlay r r inter-l v l or int r-lay r) near30 liner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:16
-	64	((insulat r or insulating r di l ctric) n ar30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:16
-	4	((insulator or insulating or dielectric) near30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer))) and (oxide near10 liner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:16
-	4	((insulator or insulating or dielectric) near30 (polysilicon or poly-silicon) near30 oxide near30 (spacer or sidewall) near30 (interlevel or interlayer or inter-level or inter-layer))) and liner	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:16
-	76	((insulator or insulating or dielectric) near50 (polysilicon or poly-silicon) near50 oxide near50 (spacer or sidewall) near50 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:17
-	4	((insulator or insulating or dielectric) near50 (polysilicon or poly-silicon) near50 oxide near50 (spacer or sidewall) near50 (interlevel or interlayer or inter-level or inter-layer))) and liner	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:17
-	82	((insulator or insulating or dielectric) near100 (polysilicon or poly-silicon) near100 oxide near100 (spacer or sidewall) near100 (interlevel or interlayer or inter-level or inter-layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:19
-	4	((insulator or insulating or dielectric) near100 (polysilicon or poly-silicon) near100 oxide near100 (spacer or sidewall) near100 (interlevel or interlayer or inter-level or inter-layer))) and liner	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:18
-	2	((insulator or insulating or dielectric) near100 (polysilicon or poly-silicon) near100 oxide near100 (spacer or sidewall) near100 (interlevel or interlayer or inter-level or inter-layer))) and L-shaped	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:19
-	5	((insulator or insulating or dielectric) near100 (polysilicon or poly-silicon) near100 oxide near100 (spacer or sidewall) near100 (int rlevel or interlayer or int r-level or inter-layer))) and (spacer near5 shap d)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 11:21

-	206	L-shaped near spac r	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:00
-	0	altair and nan t chnol gi s	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:47
-	0	altair and nanotech	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:48
-	227	altair	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:49
-	30	altair.asnm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:54
-	0	small near technology near venture near capital	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:55
-	1073	harris near harris	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:56
-	0	(harris near harris).asnm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:56
-	54375	harris adj harris	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:57
-	322	(harris adj harris) and nano	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:59

-	3	(harris n ar harris) and nano	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 13:59
-	206	L-shap d near spac r	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:01
-	8	(L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:03
-	7	((L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and liner	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:03
-	7	((((L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and liner) and ((insulator or insulating or dielectric) near10 substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:04
-	6	(((((L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and liner) and ((insulator or insulating or dielectric) near10 substrate)) and ((polysilicon or poly-silicon) near10 (insulating or insulator or dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:05
-	6	((((((L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-level or interlayer or inter-layer)) and liner) and ((insulator or insulating or dielectric) near10 substrate)) and ((polysilicon or poly-silicon) near10 (insulating or insulator or dielectric))) and ((polysilicon or poly-silicon) near10 (liner or oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:06

-	5	((((L-shaped near spacer) and (insulator or insulating or dielectric) and (polysilicon or poly-silicon) and (liner or oxide) and spacer and sidewall and (interlevel or inter-layer) or interlayer or inter-layer) and (liner) and ((insulator or insulating or dielectric) near10 substrate)) and ((polysilicon or poly-silicon) near10 (insulating or insulator or dielectric))) and ((polysilicon or poly-silicon) near10 (liner or oxide))) and ((spacer or sidewall) near20 (polysilicon or poly-silicon) near20 (liner or oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:22
-	226091	(insulator or insulating or dielectric) near20 substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:23
-	16063	((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:24
-	112	((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:25
-	25	((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:28
-	7	((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)) and (interlevel or inter-level or interlayer or inter-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:28
-	23	((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)) and ((dielectric or insulating or insulator) near20 (polysilicon or poly-silicon))) and (liner near20 oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:30

-	19	((((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)) and ((dielectric or insulating or insulator) near20 (polysilicon or poly-silicon))) and (liner near oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:31
-	6	((((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)) and ((dielectric or insulating or insulator) near20 (polysilicon or poly-silicon))) and (liner near oxide) and (liner near oxide near10 angstrom)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:32
-	25	((((insulator or insulating or dielectric) near20 substrate) and ((polysilicon or poly-silicon) near20 (insulating or insulator or dielectric))) and (liner near20 (polysilicon or poly-silicon))) and (spacer near20 (polysilicon or poly-silicon) near20 liner)) and ((dielectric or insulating or insulator) near20 (polysilicon or poly-silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 14:33